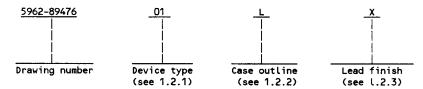
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DESC FORM 193																				

<u>DISTRIBUTION STATEMENT A.</u> Approved for public release; distribution is unlimited.

5962-E608-92

# 1. SCOPE

- 1.1 <u>Scope</u>. This drawing describes device requirements for class B microcircuits in accordance with 1.2.1 of MIL-STD-883, "Provisions for the use of MIL-STD-883 in conjunction with compliant non-JAN devices".
  - 1.2 Part or Identifying Number (PIN). The complete PIN shall be as shown in the following example:



1.2.1 Device type(s). The device type(s) shall identify the circuit function as follows:

Device type	Generic number	1/	Circuit function	Propagation delay
01			16-Macrocell EPLD	35 ns
02			16-Macrocell EPLD	25 ns
03			16-Macrocell EPLD	15 ns

1.2.2 <u>Case outline(s)</u>. The case outline(s) shall be as designated in MIL-STD-1835 and as follows:

Outline letter	Descriptive designator	<u>Terminals</u>	Package style
Ļ	GDIP3-T24, CDIP4-T24	24	Dual-in-line package 2/
X	GQCC1-J28	28	"J" lead chip carrier 2/

1.2.3 <u>Lead finish</u>. The lead finish shall be as specified in MIL-M-38510. Finish letter "X" shall not be marked on the microcircuit or its packaging. The "X" designation is for use in specifications when lead finishes A, B, and C are considered acceptable and interchangeable without preference.

1.3 Absolute maximum ratings. 3/

Supply voltage range (V <sub>CC</sub> )	-2.0 V dc to +7.0 V dc
Supply voltage range (V <sub>CC</sub> ) Programming supply voltage range (V <sub>PP</sub> )	-2.0 V dc to +13.5 V dc 4/
DC input voltage range	-2.0 V dc to +7.0 V dc 4/
Maximum power dissipation	1.0 w <u>5</u> /
Lead temperature (soldering, 10 seconds)	+260°c
Thermal resistance, junction-to-case $(\theta_{ic})$ :	
Case outlines L and X	See MIL-STD-1835
Junction temperature $(T_j)$	+175°C
Storage temperature range	-65°C to +150°C
Temperature under bias range	-55°C to +125°C
Endurance	25 erase/write cycles (minimum)
Data retention	10 years (minimum)

 $\underline{5}$ / Must withstand the added P<sub>D</sub> due to short circuit test (e.g., I<sub>OS</sub>).

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<sup>1/</sup> Generic numbers are listed on the Standardized Military Drawing Source Approval Bulletin at the end of this document and will also be listed in MIL-BUL-103.

 $<sup>\</sup>underline{2}$ / Lid shall be transparent to permit ultraviolet light erasure.

Stresses above the absolute maximum rating may cause permanent damage to the device. Extended operation at the maximum levels may degrade performance and affect reliability.
 Minimum dc input voltage is -0.5 V. During transitions, inputs may undershoot to -2.0 V for periods less

 $<sup>\</sup>frac{4}{}$  Minimum dc input voltage is -0.5 V. During transitions, inputs may undershoot to -2.0 V for periods less than 20 ns. Maximum dc voltage on output pins is  $V_{CC}$  + 0.5 V, which may overshoot to +7.0 V for periods less than 20 ns under no load conditions.

1.4	Recommended operating conditions.
	Supply voltage range ( $V_{CC}$ ) +4.5 V dc to +5.5 V dc Ground voltage (GND) 0 V dc Input high voltage ( $V_{IH}$ ) 2.0 V dc minimum Input low voltage ( $V_{IL}$ ) 0.8 V dc maximum Case operating temperature range ( $T_{C}$ ) 55°C to +125°C <u>6</u> / Input rise time ( $T_{C}$ ) 50 ns maximum Input fall time ( $T_{C}$ ) 50 ns maximum
2.	APPLICABLE DOCUMENTS
speci Index	Government specification, standards, and bulletin. Unless otherwise specified, the following ification, standards, and bulletin of the issue listed in that issue of the Department of Defense of Specifications and Standards specified in the solicitation, form a part of this drawing to extent specified herein.

SPECIFICATION

MILITARY

MIL-M-38510

- Microcircuits, General Specification for.

**STANDARDS** 

MILITARY

MIL-STD-883

- Test Methods and Procedures for Microelectronics.

MIL-STD-1835

Microcircuit Case Outlines.

BULLETIN

**MILITARY** 

MIL-BUL-103

- List of Standardized Military Drawings (SMDs).

(Copies of the specification, standards, and bulletin required by manufacturers in connection with specific acquisition functions should be obtained from the contracting activity or as directed by the contracting activity.)

2.2 Order of precedence. In the event of a conflict between the text of this drawing and the references cited herein, the text of this drawing shall take precedence.

## 3. REQUIREMENTS

- 3.1 <u>Item requirements</u>. The individual item requirements shall be in accordance with 1.2.1 of MIL-STD-883, "Provisions for the use of MIL-STD-883 in conjunction with compliant non-JAN devices" and as specified herein.
- 3.2 <u>Design, construction, and physical dimensions</u>. The design, construction, and physical dimensions shall be as specified in MIL-M-38510 and herein.
  - 3.2.1 <u>Case outline(s)</u>. The case outline(s) shall be in accordance with 1.2.2 herein.
  - 3.2.2 <u>Terminal connections</u>. The terminal connections shall be as specified on figure 1.
  - 3.2.3 Truth table(s). The truth table(s) shall be as specified on figure 2.

6/ Case temperatures are instant on.

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- 3.2.3.1 <u>Unprogrammed or erased devices</u>. The truth table for unprogrammed devices for contracts involving no altered item drawing shall be as specified on figure 2. When required in screening (see 4.2 herein) or qualification conformance inspection, groups A, B, C, or D (see 4.3 herein), the devices shall be programmed by the manufacturer prior to test. A minimum of 50 percent of the total number of cells shall be programmed or at least 25 percent of the total number of cells to any altered item drawing.
- 3.2.3.2 <u>Programmed devices</u>. The truth table for programmed devices shall be as specified by an attached altered item drawing.
- 3.3 <u>Electrical performance characteristics</u>. Unless otherwise specified herein, the electrical performance characteristics are as specified in table I and shall apply over the full case operating temperature range.
- 3.4 <u>Electrical test requirements</u>. The electrical test requirements shall be the subgroups specified in table II. The electrical tests for each subgroup are described in table I.
- 3.5 <u>Marking</u>. Marking shall be in accordance with MIL-STD-883 (see 3.1 herein). The part shall be marked with the PIN listed in 1.2 herein. In addition, the manufacturer's PIN may also be marked as listed in MIL-BUL-103 (see 6.6 herein).
- 3.6 <u>Certificate of compliance</u>. A certificate of compliance shall be required from a manufacturer in order to be listed as an approved source of supply in MIL-BUL-103 (see 6.6 herein). The certificate of compliance submitted to DESC-EC prior to listing as an approved source of supply shall affirm that the manufacturer's product meets the requirements of MIL-STD-883 (see 3.1 herein) and the requirements herein.
- 3.7 <u>Certificate of conformance</u>. A certificate of conformance as required in MIL-STD-883 (see 3.1 herein) shall be provided with each lot of microcircuits delivered to this drawing.
- 3.8 Notification of change. Notification of change to DESC-EC shall be required in accordance with MIL-STD-883 (see 3.1 herein).
- 3.9 <u>Verification and review</u>. DESC, DESC's agent, and the acquiring activity retain the option to review the manufacturer's facility and applicable required documentation. Offshore documentation shall be made available onshore at the option of the reviewer.
- 3.10 <u>Processing EPLD's</u>. All testing requirements and quality assurance provisions herein shall be satisfied by the manufacturer prior to delivery.
- 3.10.1 <u>Erasure of EPLD's</u>. When specified, devices shall be erased in accordance with the procedures and characteristics specified in 4.4.
- 3.10.2 <u>Programmability of EPLD's</u>. When specified, devices shall be programmed to the specified pattern using the procedures and characteristics specified in 4.5.
- 3.10.3 <u>Verification of erasure or programmed EPLD's</u>. When specified, devices shall be verified as either programmed (see 4.5 herein) to the specified pattern or erased (see 4.4 herein). As a minimum, verification shall consist of performing a functional test (subgroup 7) to verify that all bits are in the proper state. Any bit that does not verify to be in the proper state shall constitute a device failure, and shall be removed from the lot.
- 3.11 <u>Endurance</u>. A reprogrammability test shall be completed as part of the vendors reliability monitors, this reprogrammability test shall be done only for initial characterization and after any design or process changes which may affect the reprogrammability of the device. This test shall consist of 25 program/erase cycles on 25 devices with the following conditions:
  - a. All devices selected for testing shall be programmed in accordance with 3.2.3.1 herein.
  - b. Verify pattern (see 3.10.3).
  - c. Erase (see 3.10.1).
  - d. Verify pattern erasure (see 3.10.3).

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STANDARDIZED MILITARY DRAWING			SIZE				5962	-8947	
See footnotes at end of table	•								
Functional tests		   See 4.3.1d		7, 8	ALL			   	
Clk/V <sub>PP</sub> capacitance <u>2</u> /	C <sub>VPP</sub>	V <sub>CC</sub> = 5.0 V, V <sub>OL</sub> T <sub>A</sub> = +25°C, f = (see 4.3.1c)	JT = 0.0 V, 1 MHz	4	All		50	pF	
Output capacitance <u>2</u> /	Соит	V <sub>CC</sub> = 5.0 V, V <sub>OL</sub> T <sub>A</sub> = +25°C, f = (see 4.3.1c)	JT = 0.0 V, 1 MHz	4	ALL		20	pF	
Input capacitance <u>2</u> /	c <sub>IN</sub>	V <sub>CC</sub> = 5.0 V, V <sub>IN</sub> T <sub>A</sub> = +25°C, f = (see 4.3.1c)	1 = 0.0 V, 1 MHz	4	ALL		20	   pF 	
(standby, nonturbo)	1 003	V <sub>CC</sub> = 5.5 V, I <sub>OU</sub> V <sub>IN</sub> = GND	· · · · · · · · · · · · · · · · · · ·		02,03		150	   	
Power supply current 4/5/	I <sub>CC3</sub>	V <sub>CC</sub> = 5.5 V, I <sub>CC</sub>	= O mA,	1, 2, 3	01		900	     μΑ	
Power supply current (turbo-off) <u>2</u> / <u>4</u> /	I <sub>cc2</sub>	V <sub>CC</sub> = 5.5 V, I <sub>OU</sub> V <sub>IN</sub> = V <sub>CC</sub> or GND f = 1 MHz	T - 0 IIIA/	,, ,, ,	02,03		10		
Over supply current   I   Va = 5.5 V. Iau		1944 V	1, 2, 3	01	<u> </u>	25	   mA		
Power supply current (turbo-on) <u>2/4/</u>	I cc1	$V_{CC} = 5.5 \text{ V, } I_{OU}$ $V_{IN} = V_{CC} \text{ or GND}$ $f = 1/t_{PD}$	T = U MA,	1, 2, 3	02,03		140     300	mA   	
Output short circuit current <u>2</u> / <u>3</u> /	Isc	V <sub>CC</sub> = 5.5 V, V <sub>OUT</sub> = 0.5 V	- 0 .	1, 2, 3	ALL	-30	140	mA	
Output leakage current	Ioz	V <sub>CC</sub> = 5.5 V, V <sub>OUT</sub> = 5.5 V and	GND	1, 2, 3	ALL	-10	10	μΑ	
Input leakage current	IIX	V <sub>CC</sub> = 5.5 V, V <sub>IN</sub> = 5.5 V and	GND	1, 2, 3	ALL	   -10 	10	μА	
Input low voltage 1/2/	V <sub>IL</sub>			1, 2, 3	All	-0.3	0.8	٧	
Input high voltage <u>1</u> / <u>2</u> /	V <sub>IH</sub>			1, 2, 3	ALL	2.0	V <sub>CÇ</sub>   +0.3	٧	
Output low voltage	v <sub>oL</sub>	V <sub>CC</sub> = 4.5 V, V <sub>IH</sub> I <sub>OL</sub> = 4.0 mA, V <sub>I</sub>	= 2.0 V, L = 0.8 V	1, 2, 3	   All		0.45	V	
Output high voltage	v <sub>он</sub>	V <sub>CC</sub> = 4.5 V, V <sub>IH</sub> I <sub>OH</sub> = -4.0 mA, V	= 2.0 V, IL = 0.8 V	1, 2, 3	All	2.4		V	
Test	Symbol	-55°C ≤ T <sub>C</sub> 4.5 V ≤ V <sub>C</sub> unless otherw	≤ +125°C c ≤ 5.5 V ise specified	Group A subgroups	Device   types	   Min	Max	Unit	
	1	Condition		1	<u> </u>	Lim	its		

		Condition	s			Lim	its	Uni+	
Test	Symbol	-55°C ≤ T <sub>C</sub> 4.5 V ≤ V <sub>CC</sub> unless otherwi	≤ +125°C ≤ 5.5 V se_specified	Group A subgroups	Device   types 	Min	Max	Unit	
	Exte	ernal synchronous sw		cteristics					
		_			01	]	35		
Input to nonregistered output <u>6</u> / <u>10</u>	t <sub>PD</sub>	See figures 3 and CL = 30 pF	1 4 <u>/</u> /	9, 10, 11	02		25	ns	
					03		15		
		1			01		35		
Input to output enable	t <sub>PŽX</sub>			9, 10, 11	02		25	ns	
<u>8</u> / <u>10</u> /					03		18	! 	
Total disable		   See figures 3 and	1 / 7/		01		35	ns	
Input to output disable	t <sub>PXZ</sub>	C <sub>L</sub> = 5 pF	1 4 <u>r</u> /	9, 10, 11	02		25	115	
<u>8</u> / <u>9</u> / <u>10</u>					03	1	18		
A complementation and the second		See figures 3 and	1 / 7/	9, 10, 11	01		37	ns	
Asynchronous output clear time 10/	CLR	C <sub>L</sub> = 30 pF	, , <u>r</u> ,	,, 10, 11	02		25	į	
<u>10</u> /					03		18		
Input setup time	+	<del> </del>   		9, 10, 11	01	27		ns	
10/	tsu			,, 10, 11	02	15			
		1			03	12			
Input hold time	t <sub>H</sub>	1		9, 10, 11	ALL	0		ns	
		<u> </u>		1	01	12	<u> </u>	   _  ns	
Clock high time 9/	t <sub>CH</sub>			9, 10, 11	02	6			
					03	5	<del>                                     </del>	.	
		1			01	12	<u> </u>		
Clock low time 9/	tcL			9, 10, 11	02	6	<del>                                     </del>	ns	
					03	5		.	
		†		10.45.45	01		22		
Clock to output delay <u>6</u> /	t co1			9, 10, 11	02		10	. ns	
					03		8	-	
See footnotes at end of table									
STANDAF MILITARY	DRAWING		SIZE				5962	-8947	
DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO 45444			<del></del>			-+			

Test	Symbol	Condit	ions	  Group A	  Device	Lim	its	11-23
		4.5 V ≤ unless othe	T <sub>C</sub> ≤ +125°C V <sub>CC</sub> ≤ 5.5 V rwise specified	subgroups	types	Min	Max	Unit
Minimum clock period (register	t <sub>CNT</sub>	   See figures 3		9, 10, 11	01		35	ns
output feedback to register input, internal path)	••••	C <sub>L</sub> = 30 pF	_		02		25	MHz
<u>2</u> / <u>4</u> /	ļ	<u> </u>			03	<u> </u>	25	
Maximum frequency (1/t <sub>SU</sub> )	f <sub>MAX</sub>			9, 10, 11	01	37		
6/ Q/ 11/					02	66.7		
<u>6</u> / <u>9</u> / <u>11</u> /		<u> </u>			03	83.3		<u> </u>
Minimum clock period (tSU + tCO1) 12/	t <sub>P2</sub>			9, 10, 11	01		49	ns
<u>12</u> /		   			02		25	
	<u> </u>	1		1	03     01	28.5	20	<u> </u>
Internal maximum frequency (1/t <sub>CNT</sub> ) 4/9/	fcnt			9, 10, 11	01	28.5		MHz
CN1" = = =					02	66		]   
	<u> </u>	<u> </u> 		<u> </u>	03	8		
Asynchronous input setup time <u>2</u> / <u>10</u> /	t <sub>ASU</sub>	<u> </u> 		9, 10, 11	02	5		ns
- <b>-</b>	j I			j	03	4		
	<u> </u> 	<u>[</u>		<u> </u>	01	1 12		
Asynchronous input hold time $\underline{2}/\underline{10}/$	t <sub>AH</sub>			9, 10, 11	02	8		ns
					03	   6		j i
Annual control of the last of				1	01	12		<u> </u> 
Asynchronous clock high time <u>9</u> / <u>10</u> /	<sup>t</sup> ACH			9, 10, 11	02	7		ns 
					03	6		<u> </u>
Asynchronous clock low time	    •	_			01	12	<del></del>	<u> </u>
9/ <u>10</u> /	<sup>t</sup> ACL			9, 10, 11	02	7	<del></del>	ns
					03	6		
Asynchronous clock to output	t	•		9 10 11	01		37	   na
delay <u>6/10</u> /	<sup>t</sup> ACO1			9, 10, 11   	02		25	ns
					03		16	   
ee footnotes at end of table.								
STANDARDIZED MILITARY DRAWING			SIZE				5962-	-8947
DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO 45444			<del></del>	<del>                                     </del>				

Test	Symbol	Conditions $-55^{\circ}C \leq T_{C} \leq +125^{\circ}C$	  Group A	  Device	Lim'	its	Unit
	j -	-55°C ≤ T <sub>C</sub> ≤ +125°C 4.5 V ≤ V <sub>CC</sub> ≤ 5.5 V unless otherwise specified	subgroups	types	Min	Max	
Asynchronous minimum clock	tACNT	   See figures 3 and 4 7/	9, 10, 11	01		<b>3</b> 5 	ns
period (register output feedback to register input,	ACNI	c <sub>L</sub> = 30 pF		02		25 	_
internal path) 2/4/			İ	03		15	
Asynchronous clock to output	facur		9, 10, 11	01	28.5	 	MHz
delay <u>4</u> / <u>9</u> /	ACNT			02	40	İ	
				03	66	l	i

- These are absolute values with respect to device ground and all overshoots due to system or tester noise are included.
- Tested initially and after any design or process changes that affect that parameter, and therefore shall be guaranteed to the limits specified in table I.
- For test purposes, not more than one output at a time should be shorted. Short circuit test duration should not exceed 1 second.
- Specified with device programmed as a 16-bit counter in each LAB. Tested with manufacturer test pattern and shall be made available upon request.
- With turbo bit off, device automatically enters standby mode approximately 100 ns after last input transition.
- Measured with 4 I/O switching.
- AC tests are performed with input rise and fall times of ≤ 3 ns, timing reference levels of 1.5 V, input pulse levels of 0 to 3.0 V, and the output load on figure 3.
- $t_{PXX}$  and  $t_{PXZ}$  are measured at ±0.5 V from steady-state voltage as driven by specification output load.  $t_{PXZ}$  is measured with  $c_L$  = 5 pF.
- May not be tested but shall be guaranteed to the limits specified in table I.
- $\underline{10}$ / When the turbo bit is not set, a nonturbo adder of 30 ns maximum shall apply. Parameters may not be tested in nonturbo condition, but shall be guaranteed to the limits specified. Nonturbo mode devices require one input or I/O transition to enter correct power-up state.
- $\underline{11}/$  f<sub>MAX</sub> represents the highest clock frequency for pipelined data.  $\underline{12}/$  Not tested directly, but derived from t<sub>SU</sub> and t<sub>CO1</sub>.

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Device types	ALL		
Case outlines	L	x	
Terminal number	Terminal	Terminal symbol	
1 2 3 4 4 5 6 7 8 9 10 11 12 13 14 15 16 17 18 19 20 21 22 23 24 25 26 27	CLK_/PGM  1  1/0  1/0  1/0  1/0  1/0  1/0  1/0	VCC CLK1/PGM 1 1/0 1/0 1/0 1/0 1/0 1/0 1/0 1/0 1/0 1	
22   23   24   25   26	I/0 I	I/0 I/0 I/0 I/0 I/0	

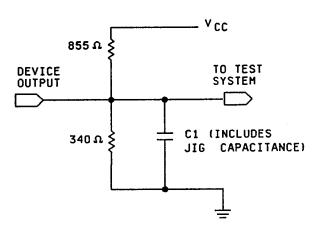
NOTE: NC = no connection.

FIGURE 1. <u>Terminal connections</u>.

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Mode	CLK <sub>2</sub> /V <sub>PP</sub>	CLK <sub>1</sub> /PGM	1/0	I
Normal operation	V <sub>IL</sub> OR V <sub>IH</sub>	VIL OR VIH	defined by application	V <sub>IL</sub> OR V <sub>IH</sub>
Program	(programming supply voltage)	V <sub>II</sub> p (program pulse)	V <sub>ILP</sub> or V <sub>IHP</sub> (data input)	V <sub>ILP</sub> to V <sub>IHP</sub> (address)
Verify	don't care	verify control	data out	V <sub>ILP</sub> to V <sub>IHP</sub> (address)

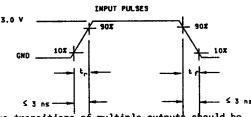
FIGURE 2. Truth table.



AC test conditions

Input pulses

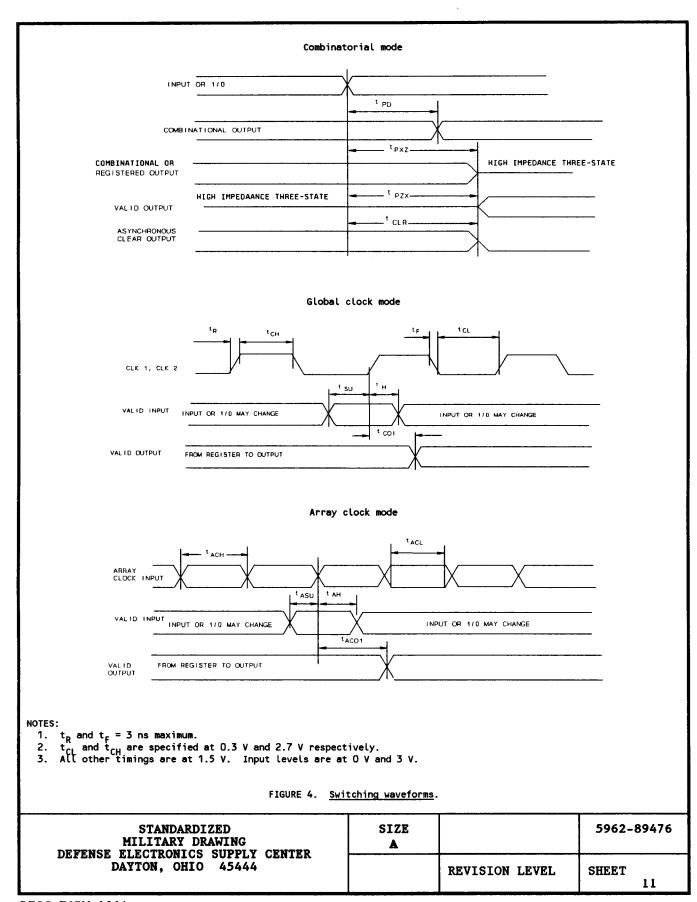
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NOTE: Power supply transients can affect ac measurements. Simultaneous transitions of multiple outputs should be avoided for accurate measurement. Threshold tests must not be performed under ac conditions. Large amplitude, fast ground current transients normally occur as the device outputs discharge the load capacitances. When these transients flow through the parasitic inductance between the device ground pin and the test system ground, it can create significant reductions in observable noise immunity.

FIGURE 3. Output load circuit and test conditions.

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### 4. QUALITY ASSURANCE PROVISIONS

- 4.1 <u>Sampling and inspection</u>. Sampling and inspection procedures shall be in accordance with section 4 of MIL-M-38510 to the extent specified in MIL-STD-883 (see 3.1 herein).
- 4.2 <u>Screening</u>. Screening shall be in accordance with method 5004 of MIL-STD-883, and shall be conducted on all devices prior to quality conformance inspection. The following additional criteria shall apply:
  - a. Burn-in test, method 1015 of MIL-STD-883.
    - (1) Test condition C or D using the circuit submitted with the certificate of compliance (see 3.6 herein).
    - (2)  $T_A = +125$ °C, minimum.
  - b. Interim and final electrical test parameters shall be as specified in table II herein, except interim electrical parameter tests prior to burn-in are optional at the discretion of the manufacturer.
  - c. A data retention stress test shall be included as part of the screening procedure and shall consist of the following steps: (Steps 1 through 4 may be performed at the wafer level. The maximum storage temperature shall not exceed +200°C for packaged devices or +300°C for unassembled devices.)

## Margin test method .

- (1) Program a minimum of 95 percent of the total number of cells, including the slowest programming cell (see 3.10.2).
- (2) Bake, unbiased, for 72 hours at +140°C or for 48 hours at +150°C or for 8 hours at +200°C or for 2 hours at +300°C for unassembled devices only.
- (3) Perform electrical test (see 4.2.b) at +25°C including a margin test at  $V_{\rm m}$  = 5.7 V and loose timing (i.e., 1  $\mu$ s).
- (4) Erase (see 3.10.1).
- (5) Program a minimum of 50 percent of the total number of cells, including the slowest programming cell (see 3.10.2).
- (6) Perform electrical test (see 4.2.b) at +25°C including a margin test at  $V_{\rm m}$  = 5.7 V and loose timing (i.e., 1  $\mu$ s).
- (7) Perform burn-in (see 4.2a).
- (8) Perform electrical test (see 4.2.b) at +25°C including a margin test at  $V_{m}$  = 5.7 V and loose timing (i.e., 1  $\mu$ s).
- (9) Perform electrical tests at  $T_C = +125$ °C.
- (10) Perform electrical tests at  $T_C = -55$ °C.
- (11) Erase (see 3.10.1). Devices may be submitted for groups A, B, C, and D testing.
- (12) Verify erasure (see 3.10.3).
- 4.3 <u>Quality conformance inspection</u>. Quality conformance inspection shall be in accordance with method 5005 of MIL-STD-883 including groups A, B, C, and D inspections. The following additional criteria shall apply.

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TABLE II. Electrical test requirements. 1/2/3/4/

     MIL-STD-883 test requirements	Subgroups   (per method   5005, table I)
  Interim electrical parameters  (pre burn-in) (method 5004)	1
	1*,2,3,7*,8A, 8B,9
Group A test requirements  (method 5005)	1,2,3,4**,7, 9,10,11
Groups C and D end-point   electrical parameters   (method 5005)	2,8A,10

- 1/ \* indicates PDA applies to subgroups 1 and 7.
- 2/ Any or all subgroups may be combined when using high-speed testers.
- 3/ \*\* see 4.3.1c.
- 4/ Subgroup 7 functional tests shall also verify that no cells are programmed for unprogrammed devices or that the altered item drawing pattern exists for programmed devices.

### 4.3.1 Group A inspection.

- a. Tests shall be as specified in table II herein.
- b. Subgroups 5 and 6 in table I, method 5005 of MIL-STD-883 shall be omitted.
- c. Subgroup 4 (C<sub>IN</sub> and C<sub>OUT</sub> measurements) shall be measured only for the initial characterization and after any process or design changes which may affect input or output capacitance. Sample size is 15 devices with no failures, and all input and output terminals tested.
- d. See 4/ of table II.

# 4.3.2 Groups C and D inspections.

- a. End-point electrical parameters shall be as specified in table II herein.
- b. Steady-state life test conditions; method 1005 of MIL-STD-883:
  - (1) The devices selected for testing shall be programmed in accordance with 3.2.3.1 herein. After completion of testing, the devices shall be erased and verified (except devices submitted for group D testing).
  - (2) Test condition C or D using the circuit submitted with the certificate of compliance (see 3.6 herein).
  - (3)  $T_A = +125$ °C, minimum.
  - (4) Test duration: 1,000 hours, except as permitted by method 1005 of MIL-STD-883.

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- 4.4 <u>Erasing procedure</u>. The recommended erasure procedure for the device is exposure to shortwave ultraviolet light which has a wavelength of 2537 angstroms. The integrated dose (i.e., UV intensity x exposure time) for erasure should be a minimum of 25\_Ws/cm. The erasure time with this dosage is approximately 35 minutes using a ultraviolet lamp with a 12000 \( \textit{LW/cm}^2 \) power rating. The device should be placed within 1 inch of the lamp tubes during erasure. The maximum integrated dose the device can be exposed to without damage is 7258 Ws/cm. (1 week at 12000 \( \textit{LW/cm}^2 \)). Exposure of the device to high intensity UV light for long periods may cause permanent damage.
- 4.5 <u>Programming procedures</u>. The programming procedures shall be as specified by the device manufacturer and shall be made available upon request.
  - PACKAGING
  - 5.1 Packaging requirements. The requirements for packaging shall be in accordance with MIL-M-38510.
  - 6. NOTES
- 6.1 <u>Intended use</u>. Microcircuits conforming to this drawing are intended for use when military specifications do not exist and qualified military devices that will perform the required function are not available for OEM application. When a military specification exists and the product covered by this drawing has been qualified for listing on QPL-38510, the device specified herein will be inactivated and will not be used for new design. The QPL-38510 product shall be the preferred item for all applications.
- 6.2 <u>Replaceability</u>. Microcircuits covered by this drawing will replace the same generic device covered by a contractor-prepared specification or drawing.
- 6.3 <u>Configuration control of SMDs</u>. All proposed changes to existing SMDs will be coordinated with the users of record for the individual documents. This coordination will be accomplished in accordance with MIL-STD-481 using DD Form 1693, Engineering Change Proposal (Short Form).
- 6.4 <u>Record of users</u>. Military and industrial users shall inform Defense Electronics Supply Center when a system application requires configuration control and the applicable SMD. DESC will maintain a record of users and this list will be used for coordination and distribution of changes to the drawings. Users of drawings covering microelectronics devices (FSC 5962) should contact DESC-EC, telephone (513) 296-6047.
- 6.5 <u>Comments</u>. Comments on this drawing should be directed to DESC-EC, Dayton, Ohio 45444, or telephone (513) 296-5377.
- 6.6 <u>Approved sources of supply</u>. Approved sources of supply are listed in MIL-BUL-103. The vendors listed in MIL-BUL-103 have agreed to this drawing and a certificate of compliance (see 3.6 herein) has been submitted to and accepted by DESC-EC.

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